



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of)
YANG, Nian, et al.)
Serial No. 10/758,173)
Filing Date: January 14, 2004)
For: IMPROVING ELECTROSTATIC)
DISCHARGE PERFORMANCE OF A)
SILICON STRUCTURE AND)
EFFICIENT USE OF AREA WITH)
ELECTROSTATIC DISCHARGE)
PROTECTIVE DEVICE UNDER THE)
PAD APPROACH AND ADJUSTMENT)
OF VIA CONFIGURATION THERETO)
TO CONTROL DRAIN JUNCTION)
RESISTANCE)

AMENDMENT AND RESPONSE TO OFFICE ACTION

Hon. Assistant Commissioner for Patents
P.O. Box No. 1450
Alexandria, Virginia 22313-1450

Sir:

In response to the Office Action mailed on January 21, 2005, please amend the above captioned patent application as follows and consider the following remarks.

There are no amendments to the specification in this responsive paper.

The Amendments to the Claims are reflected in the listing of the Claims, which begins on page 2 of this responsive paper.

The Remarks, with arguments, begin on page 8 of this responsive paper.